

/ Descriptions

SOT-89 NPN Silicon NPN transistor in a SOT-89 Plastic Package.

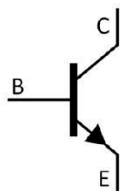
/ Features

Low saturation voltage, excellent DC current gain characteristics, complements the 2SA1797.
HF product.

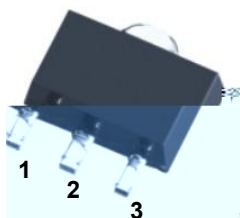
/ Applications

Low frequency power amplifier applications.

/ Equivalent Circuit



/ Pinning



PIN1	Base	PIN 2	Collector	PIN 3	Emitter
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/ **Marking**

h _{FE} Classifications Symbol	P	Q
h _{FE} Range	82 180	120 270
Marking	HDKP**	HDKQ**

/ Absolute Maximum Ratings(Ta=25)

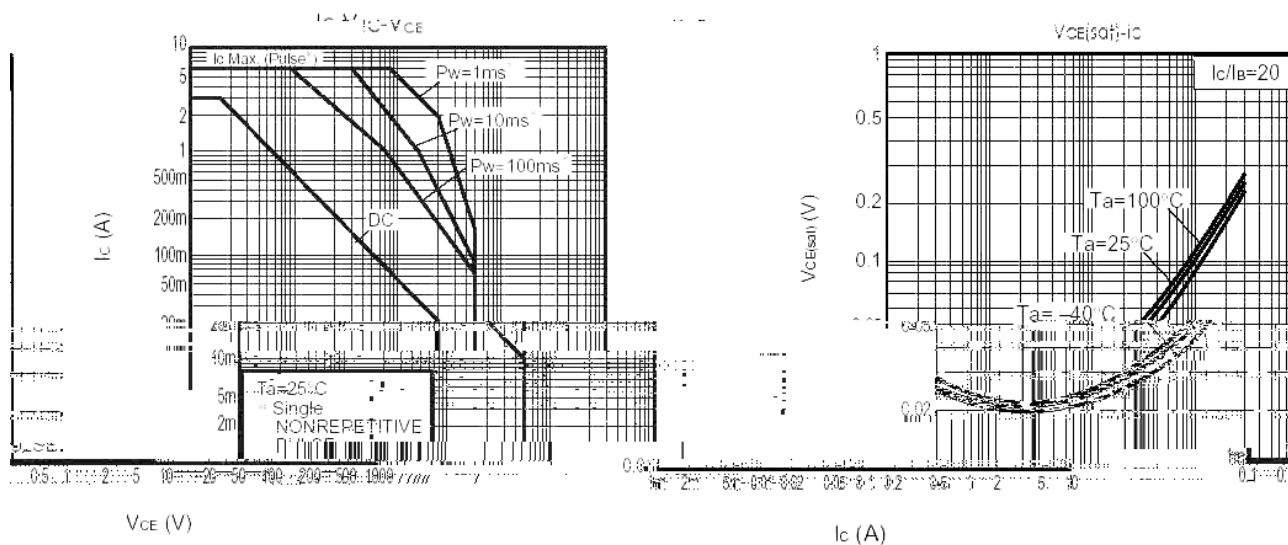
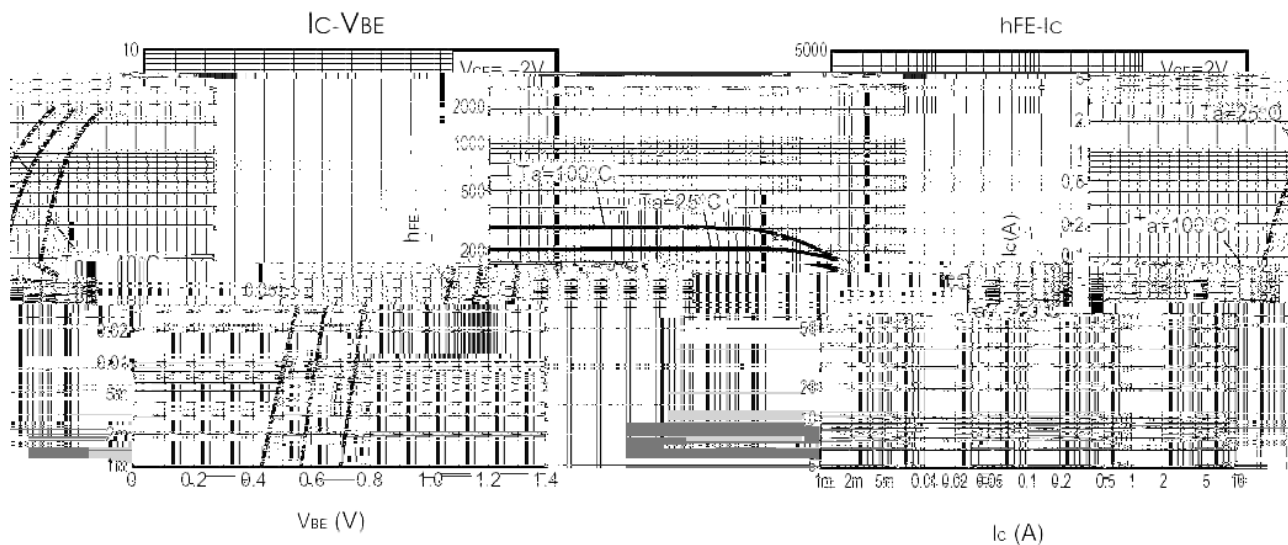
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	60	V
Collector to Emitter Voltage	V_{CEO}	50	V
Emitter to Base Voltage	V_{EBO}	6.0	V
Collector Current - Continuous	I_C	3.0	A
Collector Current – Continuous(Pulse)	I_{CP}	6.0	A
Collector Power Dissipation	P_C	0.5	W
Collector Power Dissipation*	$*P_C$	2.0	W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55 150	°C

* 40×40×0.7

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C=50\mu A$	60			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=1.0mA$	50			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E=50\mu A$	6.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=60V$			0.1	μA
Emitter Base Cut-Off Current	I_{EBO}	$V_{EB}=5.0V$			0.1	μA
DC Current Gain	$h_{FE(1)}$	$V_{CE}=2.0V$ $I_C=500mA$	82		270	
	$h_{FE(2)}$	$V_{CE}=2.0V$ $I_C=1.5A$	45			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=1.0A$ $I_B=50mA$		0.13	0.35	V
Transition Frequency	f_T	$V_{CE}=2.0V$ $I_C=0.5A$ $f=100MHz$		210		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V$ $f=1.0MHz$		25		pF

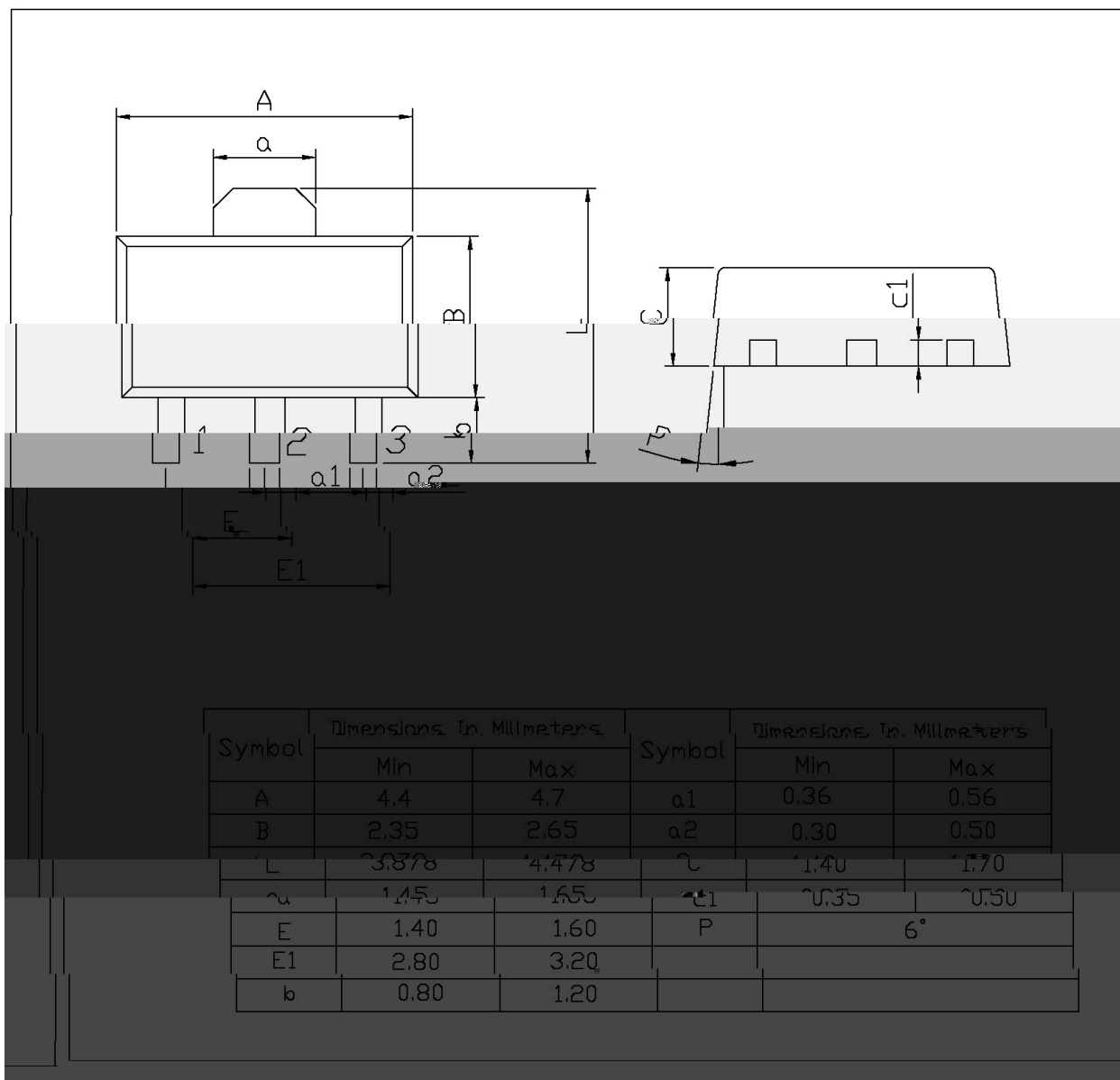
/ **Electrical Characteristic Curve**



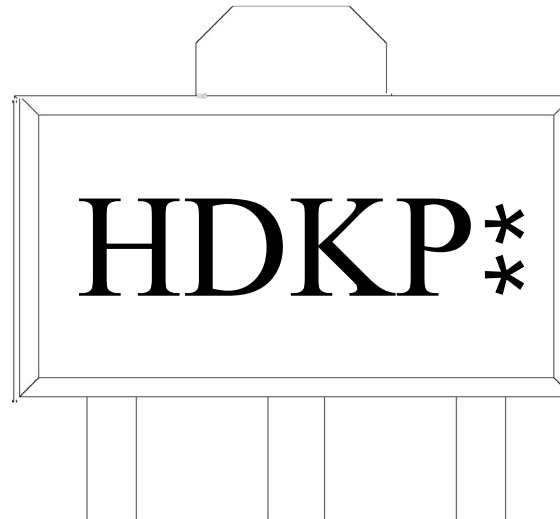
/ **Package Dimensions**

SOT-89

单位: mm



/ Marking Instructions



H

DK

P

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Note:

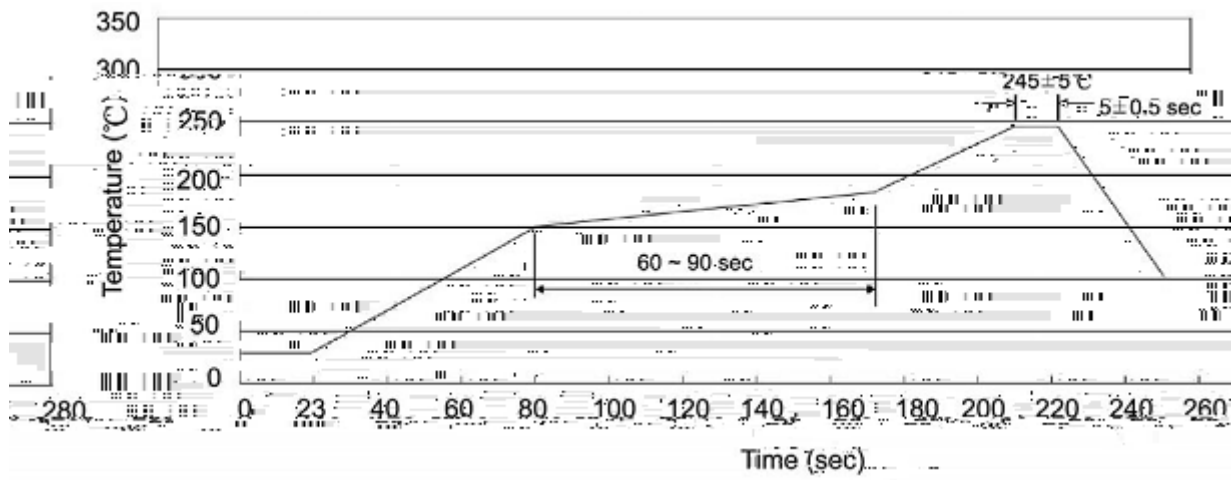
H: Company Code.

DK: Product Type.

P h_{FE} Classifications Symbol

**: Lot No. Code, code change with Lot No.

() / Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-------|-----|----|-----------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245±5 | | | 5±0.5sec; | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5℃ Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-89	1,000	7	7,000	8	56,000	7 ×12	180×120×180	385×257×392

/ Notices